## **Z0103MA**

# Logic level four-quadrant triac Rev. 03 — 5 August 2009

**Product data sheet** 

#### **Product profile** 1.

## 1.1 General description

Passivated sensitive gate 4-Q triac in a SOT54 plastic package

#### 1.2 Features and benefits

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits
- High blocking voltage of 600V
- Sensitive gate in four quadrants

## 1.3 Applications

- General purpose low power motor control
- Home appliances

- Industrial process control
- Low power AC Fan controllers

## 1.4 Quick reference data

Table 1. **Quick reference** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 38 °C; see <u>Figure 4</u> and <u>1</u>	-	-	1	А
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ T2+ G-; see <u>Figure 6</u>	-	-	3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ T2- G-	-		3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ T2+ G+	-	-	3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ T2- G+	-	-	5	mA



## Logic level four-quadrant triac

## 2. Pinning information

Table 2. Pinning information

	_			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2		<b>L</b> I
2	G	gate		T2T1
	T1	main terminal 1		sym051
			SOT54 (TO-92)	

## 3. Ordering information

Table 3. Ordering information

Type number	Package	Package			
	Name	Description	Version		
Z0103MA	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54		

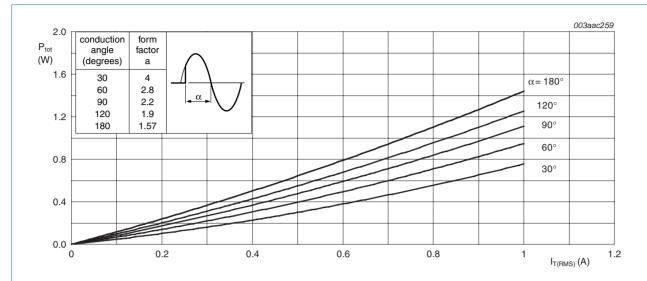
## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

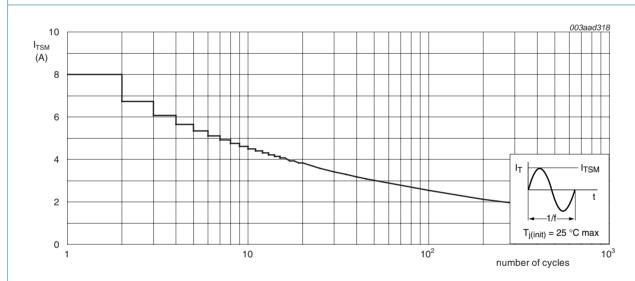
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>lead</sub> ≤ 38 °C; see <u>Figure 4</u> and <u>1</u>	-	1	Α
dI <sub>T</sub> /dt	rate of rise of on-state	$I_T = 1 \text{ A}$ ; $I_G = 20 \text{ mA}$ ; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$ ; $T2 + G + G$	-	50	A/µs
	current	$I_T = 1 \text{ A}$ ; $I_G = 20 \text{ mA}$ ; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$ ; T2- G+	-	20	A/µs
		$I_T = 1 \text{ A}$ ; $I_G = 20 \text{ mA}$ ; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$ ; $T2 + G$	-	50	A/µs
		$I_T = 1 \text{ A}$ ; $I_G = 20 \text{ mA}$ ; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$ ; T2- G-	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	1	Α
$P_{GM}$	peak gate power		-	2	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
I <sub>TSM</sub>	non-repetitive peak	full sine wave; $t_p = 16.7 \text{ ms}$ ; $T_{j(init)} = 25 \text{ °C}$	-	8.5	Α
	on-state current	full sine wave; $t_p = 20 \text{ ms}$ ; $T_{j(init)} = 25 \text{ °C}$ ; see Figure 2 and 3	-	8	Α
I <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sin-wave pulse	-	0.32	A <sup>2</sup> s
$P_{G(AV)}$	average gate power		-	0.1	W

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 $\alpha$  = conduction angle

Fig 1. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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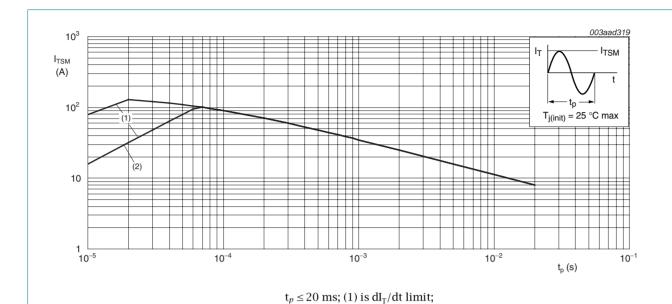
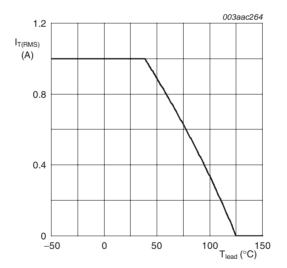


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values



(2) is T2 - G + quadrant limit

Fig 4. RMS on-state current as a function of lead temperature; maximum values

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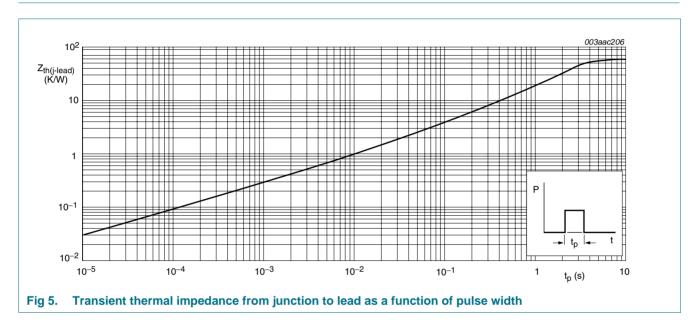
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#### **Thermal characteristics** 5.

**Thermal characteristics** Table 5.

**Product data sheet** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		-	150	-	K/W
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Full cycle; see Figure 5	-	-	60	K/W



## Logic level four-quadrant triac

## 6. Characteristics

Table 6. Characteristics

Table 0.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; } T2+ \text{ G-;}$ see Figure 6	-	-	3	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2- G-$	-	-	3	mΑ
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2+ G+	-	-	3	mΑ
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2- G+	-	-	5	mΑ
lL	latching current	$V_D = 12 \text{ V; T}_j = 25 \text{ °C; I}_G = 0.1 \text{ A; T2+ G-;}$ see Figure 7	-	-	15	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2+ G+$	-	-	7	mΑ
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2- G+$	-	-	7	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2- G-$	-	-	7	mΑ
lн	holding current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; see } Figure 10$	-	-	7	mΑ
√ <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1 A; see <u>Figure 8</u>	-	1.3	1.6	V
$V_{GT}$	gate trigger voltage	$I_T = 0.1 \text{ A}; V_D = 12 \text{ V}; T_j = 25 \text{ °C};$ see <u>Figure 9</u>	-	-	1.3	V
		$I_T = 0.1 \text{ A}; V_D = 600 \text{ V}; T_j = 125 ^{\circ}\text{C}$	0.2	-	-	V
D	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	-	0.5	mΑ
Dynamic (	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	V <sub>DM</sub> = 402 V; T <sub>j</sub> = 110 °C; gate open circuit; see <u>Figure 11</u>	10	-	-	V/µs
dV <sub>com</sub> /dt	rate of rise of commutating voltage	$V_D = 400 \text{ V}; T_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	0.5	-	-	V/µs

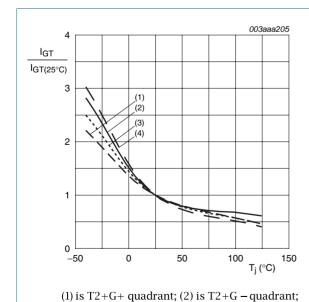


Fig 6. Normalized gate trigger current as a function of junction temperature

(3) is T2 - G – quadrant; (4) is T2 - G+ quadrant

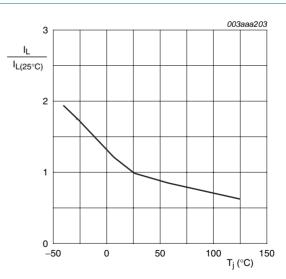
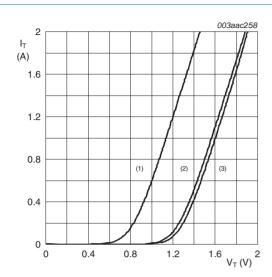


Fig 7. Normalized latching current as a function of junction temperature

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$$V_0 = 1.254 \text{ V; R}_s = 0.31 \Omega$$

- (1)  $T_j = 125$  °C; typical values
- (2)  $T_j = 125$  °C; maximum values
- (3)  $T_j = 25$  °C; maximum values

Fig 8. On-state current as a function of on-state voltage

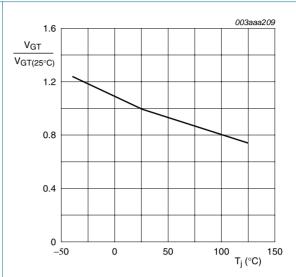


Fig 9. Normalized gate trigger voltage as a function of junction temperature

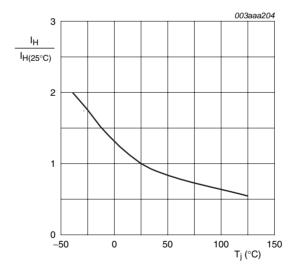


Fig 10. Normalized holding current as a function of junction temperature

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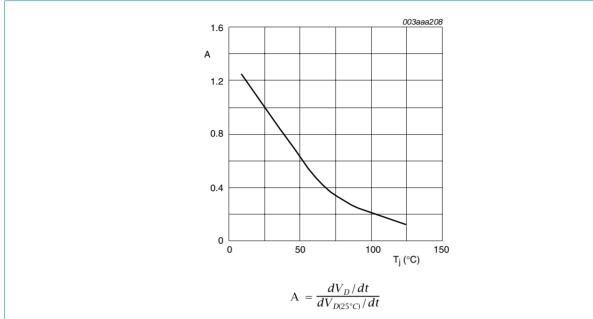
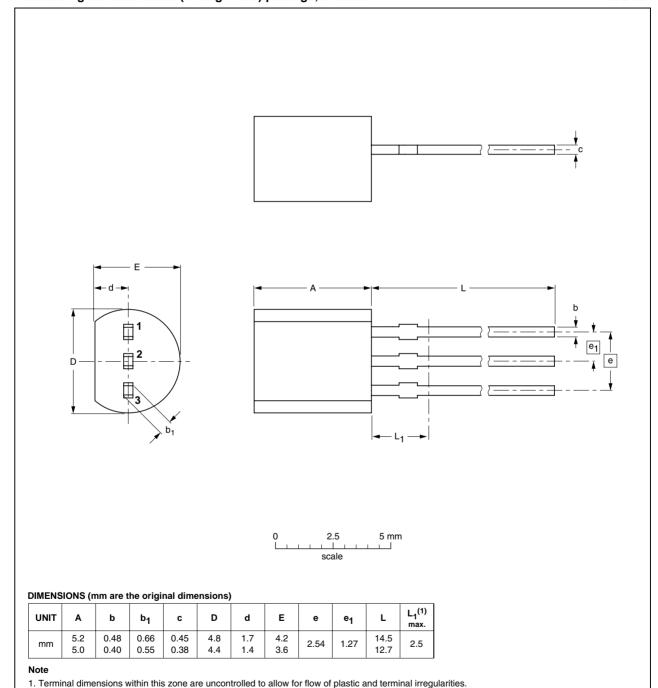


Fig 11. Normalized critical rate of rise of off-state voltage as a function of junction temperature;typical values

## 7. Package outline

## Plastic single-ended leaded (through hole) package; 3 leads

SOT54



#### Fig 12. Package outline SOT54 (TO-92)

IEC

OUTLINE

VERSION

SOT54

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**JEITA** 

SC-43A

**EUROPEAN** 

**PROJECTION** 

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ISSUE DATE

04-06-28

04-11-16

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REFERENCES

**JEDEC** 

TO-92

## Logic level four-quadrant triac

## 8. Revision history

## Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
Z0103MA_3	20090805	Product data sheet	-	Z0103_07_09_SERIES-02
Modifications:		of this data sheet has bee of NXP Semiconductors.	n redesigned to cor	mply with the new identity
	<ul> <li>Legal texts</li> </ul>	have been adapted to the	new company nam	e where appropriate.
	<ul> <li>Type numb</li> </ul>	er Z0103MA separated fro	m data sheet Z010	3_07_09_SERIES-02.
Z0103_07_09_SERIES-02 (9397 750 10102)	20020912	Product data	-	Z0103_07_09_SERIES-01
Z0103_07_09_SERIES-01 (9397 750 09419)	20020411	Product data	-	-

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Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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